



MICRO-435
Quantum and
Nanocomputing

Edoardo Charbon
Mariagrazia Graziano

M.T. BEHAVIOR & CHARACTERISTICS
PART 2

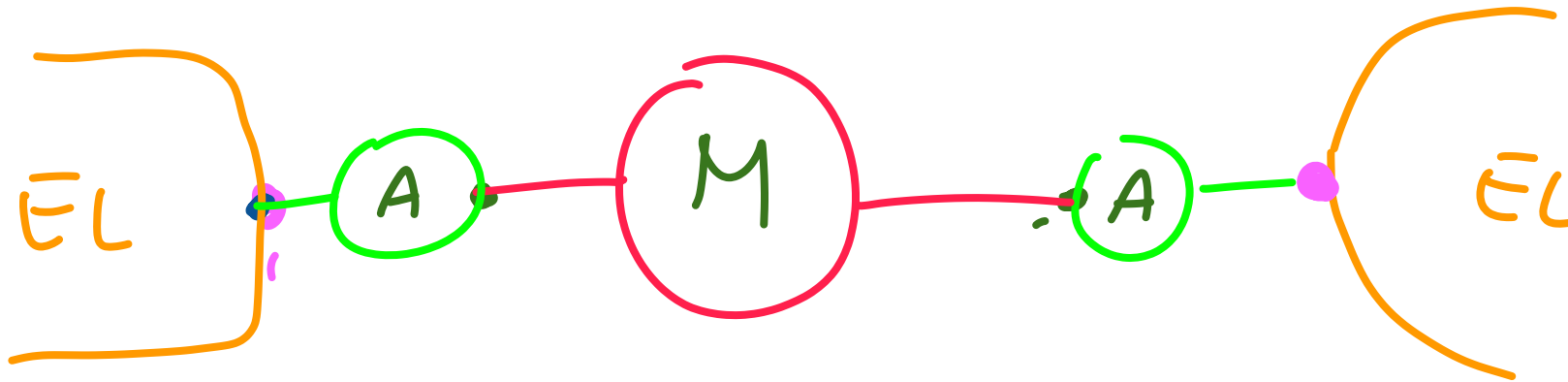
M.T. BEHAVIOR

OBJECTIVES

- a) PARAMETERS INVOLVED
- b) CHARGE SHARING, GATE
- c) SCF LOOP
- d) CIRCUITS

2) PARAMETERS INVOLVED

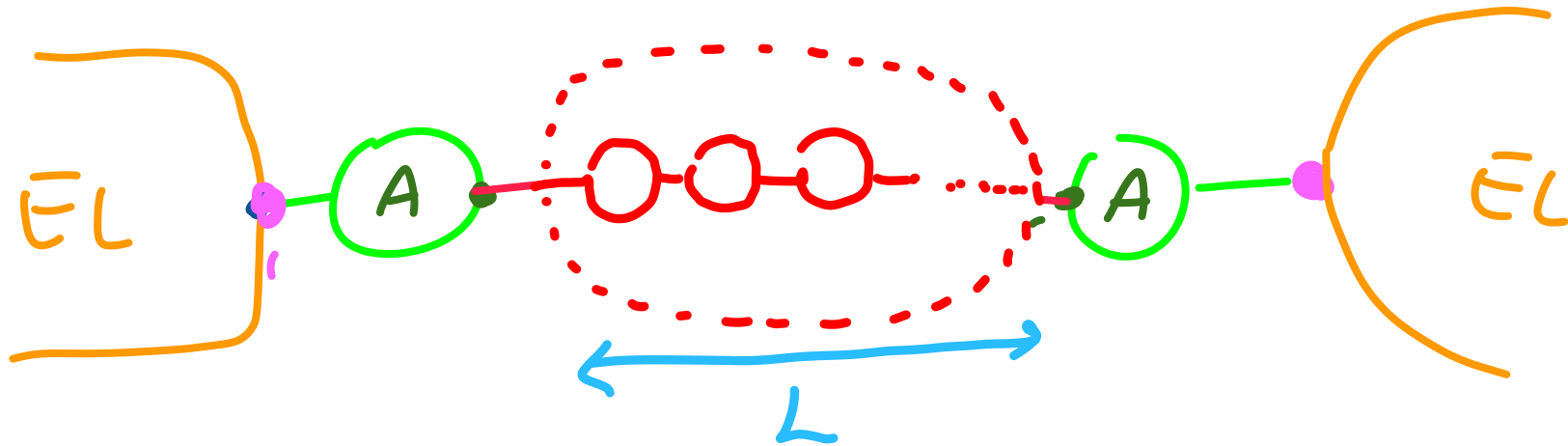
MOLECULAR TRANSISTOR



MAIN
PARAMETERS

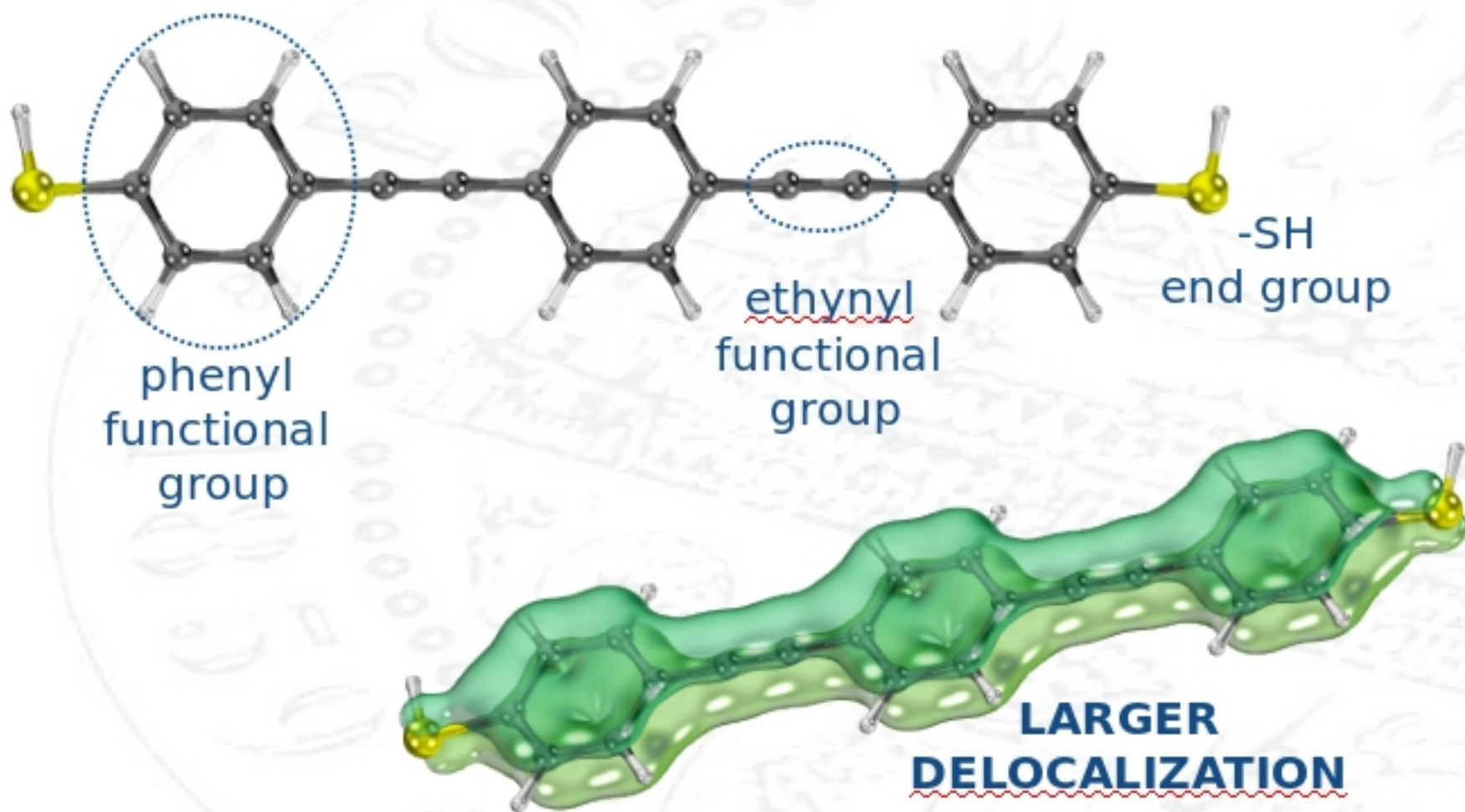
MOLECULE LENGTH
MOLECULE TORSION
ANCHORING GROUP
ELECTRODES

IMPACT OF LENGTH

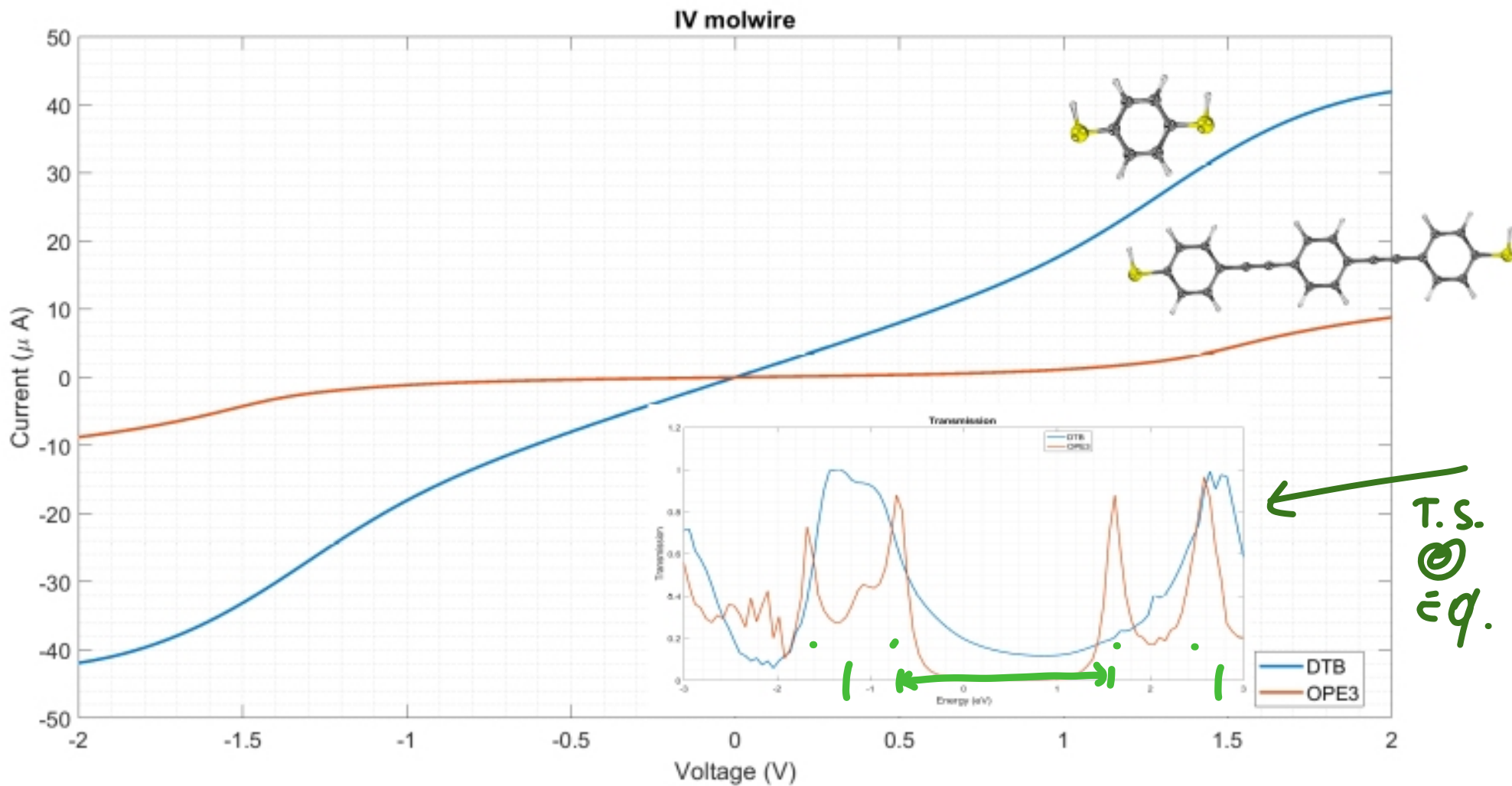


IN GENERAL IT MEANS A BIGGER
NUMBER OF RINGS IN
AROMATIC MOLECULES

LENGTH - EXAMPLE OPE3



TS AND I/V COMPARED : DTB VS OPE3



SIM. QUANTUM ATK

Why?

WE EXPECT

MORE RINGS \rightarrow MORE ATOMS \rightarrow MORE ENERGY LEVELS
 \rightarrow MORE CONDUCTIVITY \rightarrow BIGGER CURRENT

BUT IF WE OBSERVE THE $T(s)$

MORE PEAKS AS EXPECTED, BUT NARROWER

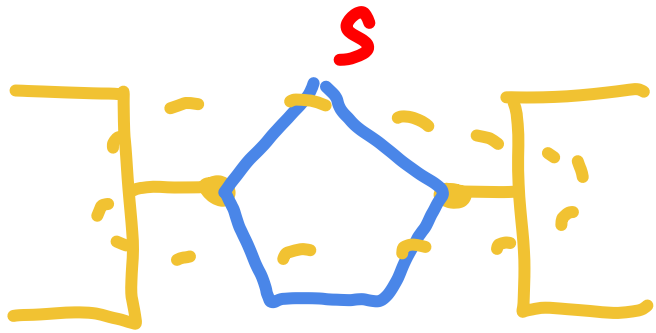
\rightarrow LESS CHARGE \rightarrow SMALLER CURRENT

NARROW PEAKS MEAN SMALLER BROADENING

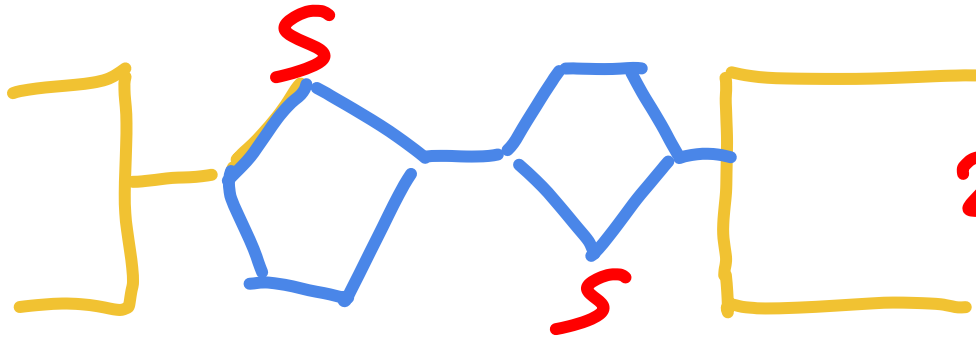
\rightarrow γ BW ELECTRODES AND MOLECULE IS REDUCED
I.E. LARGER ELECTRODES SEPARATION \rightarrow WEAK OVERLAP
BW. MOLECULE AND ELECTRODES STATES

DEPENDENCE ON LENGTH, ANOTHER EXAMPLE

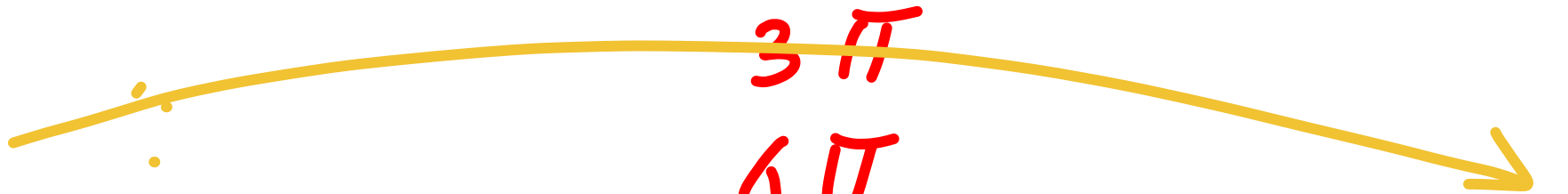
THIOPHENE (π)



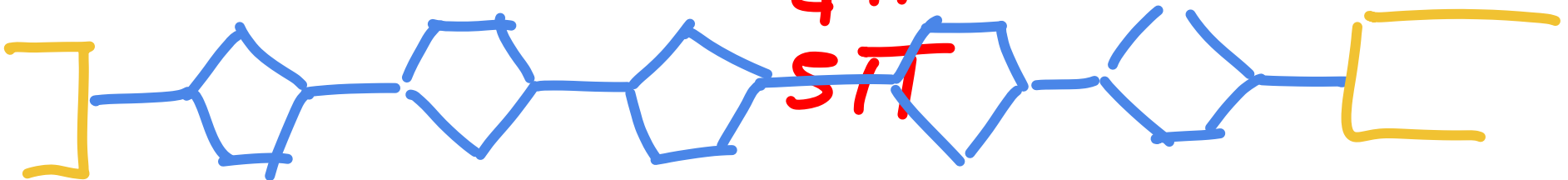
1π



2π



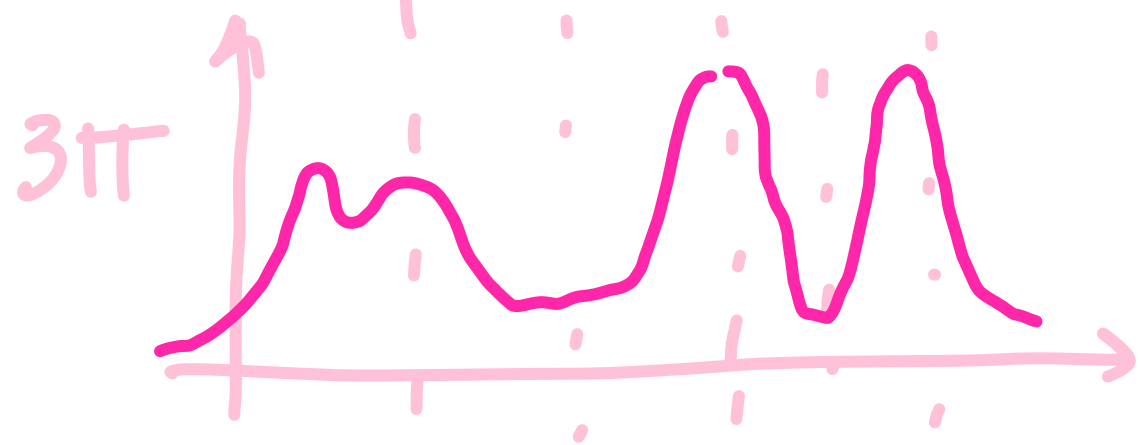
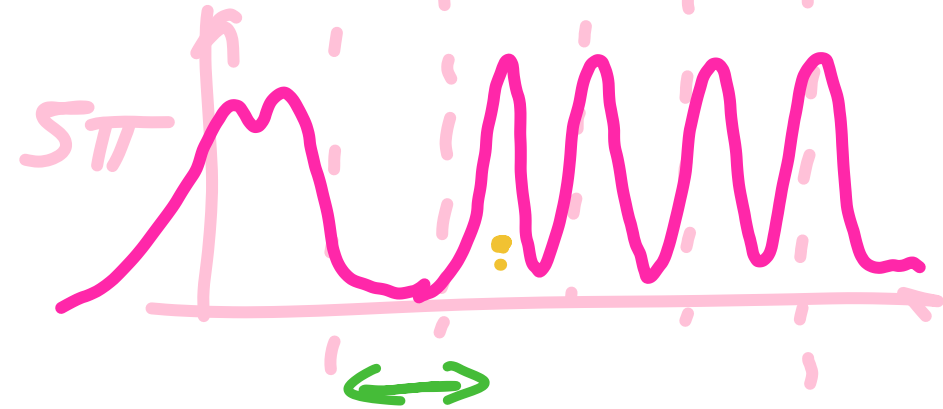
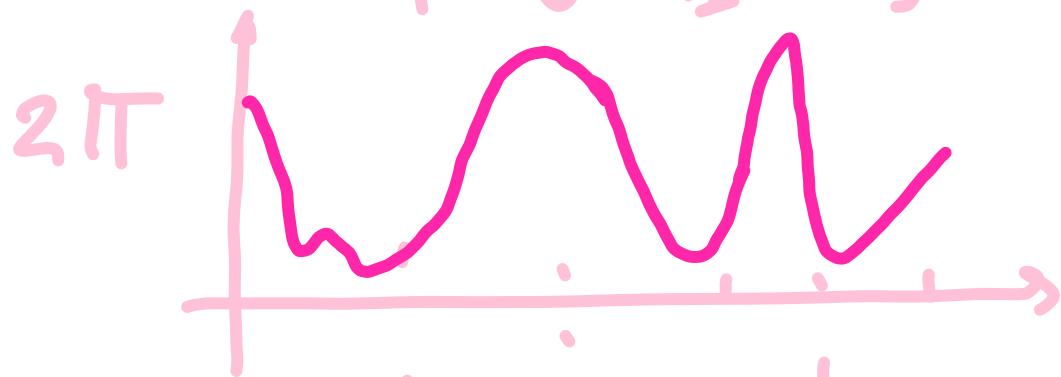
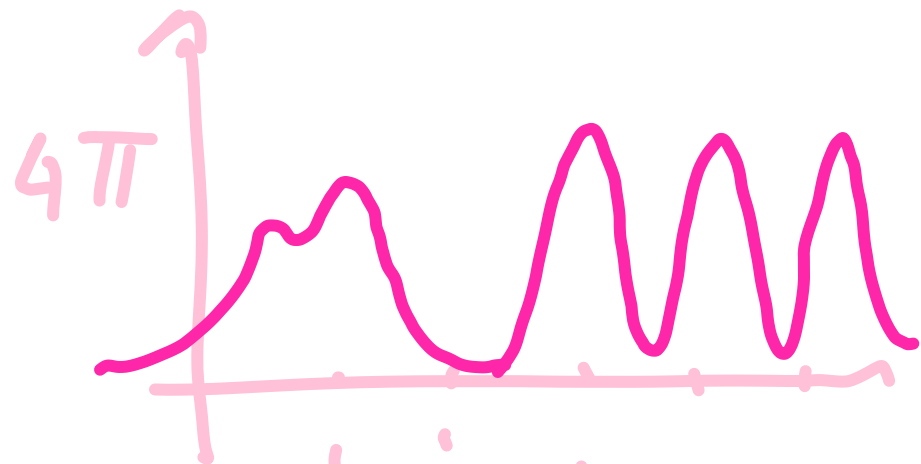
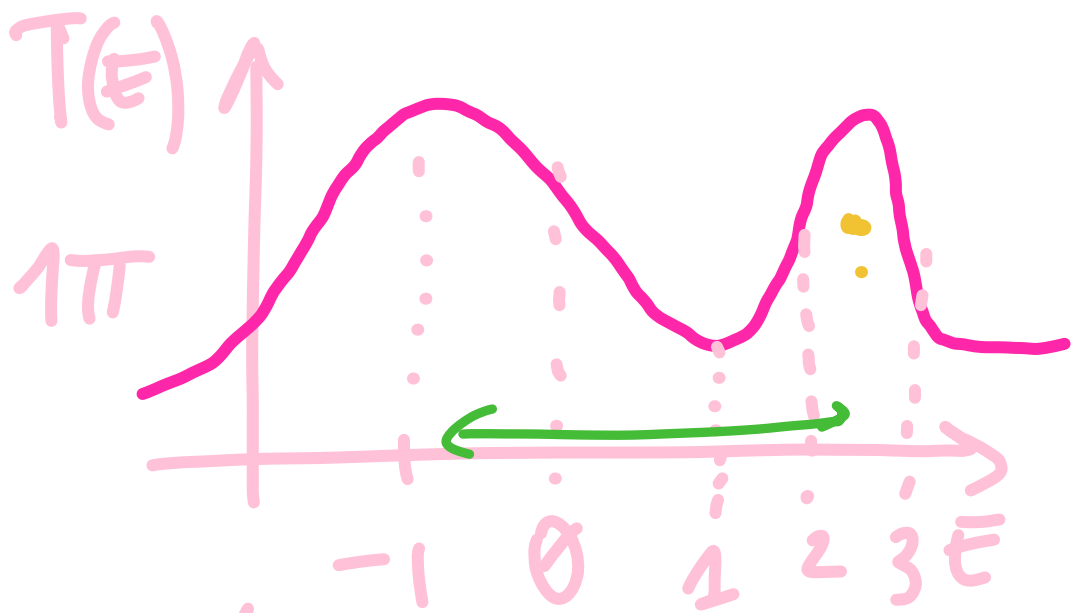
3π



4π

5π

5π



WE OBSERVE

- REDUCTION OF HLG (2V for 1π , 1V for 5π)

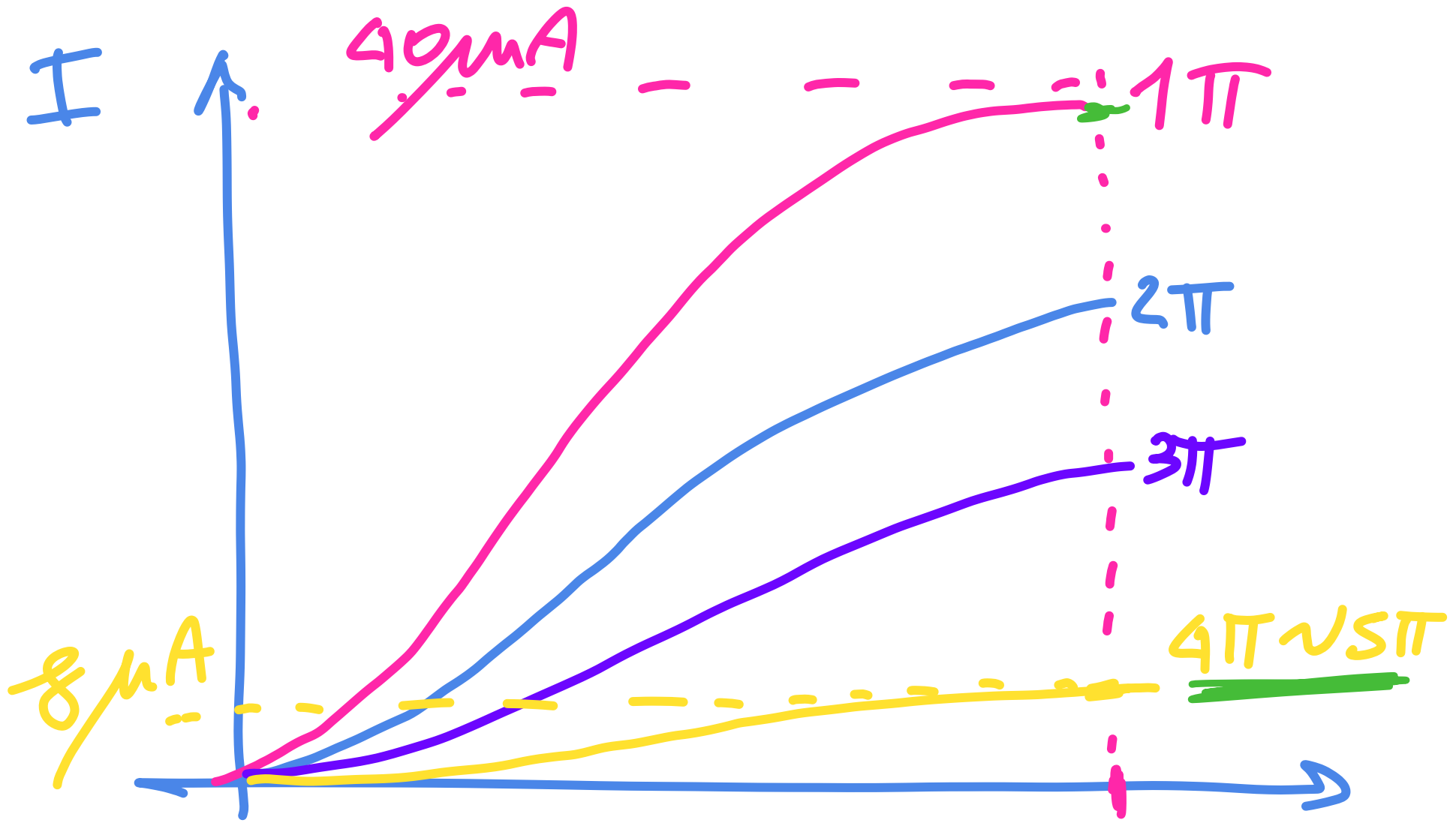
MORE RINGS \rightarrow MORE STATES \rightarrow HLG \downarrow $I \uparrow$

- MORE PEAKS

LONGER CHAIN \rightarrow MORE ELECTRONS \rightarrow MORE PEAKS $I \uparrow$

- REDUCED BROADENING

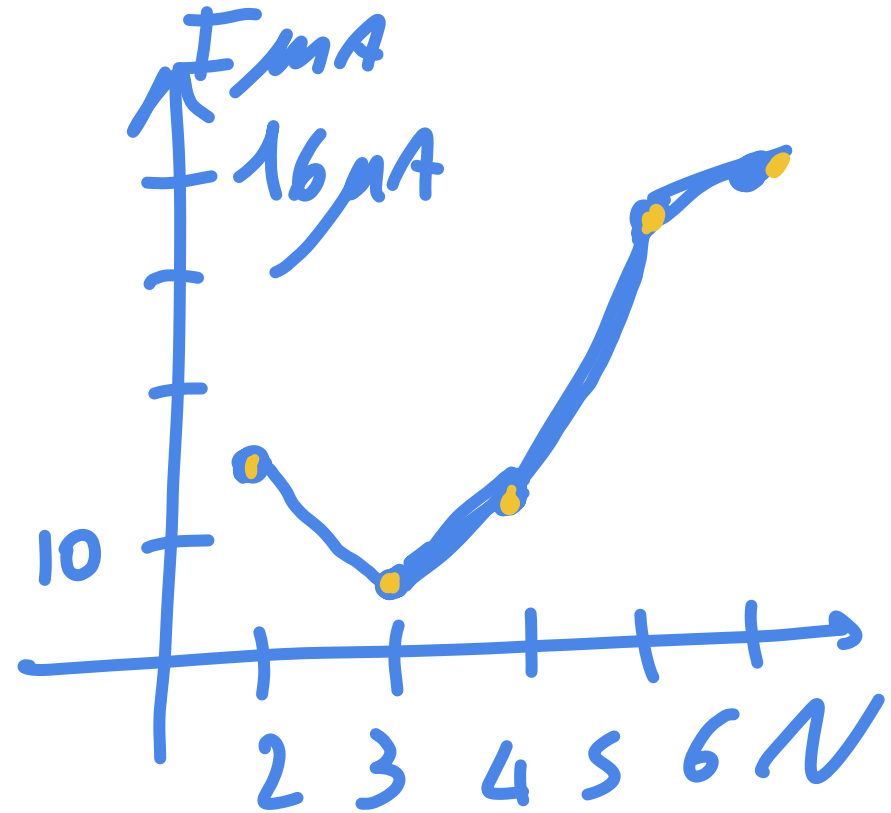
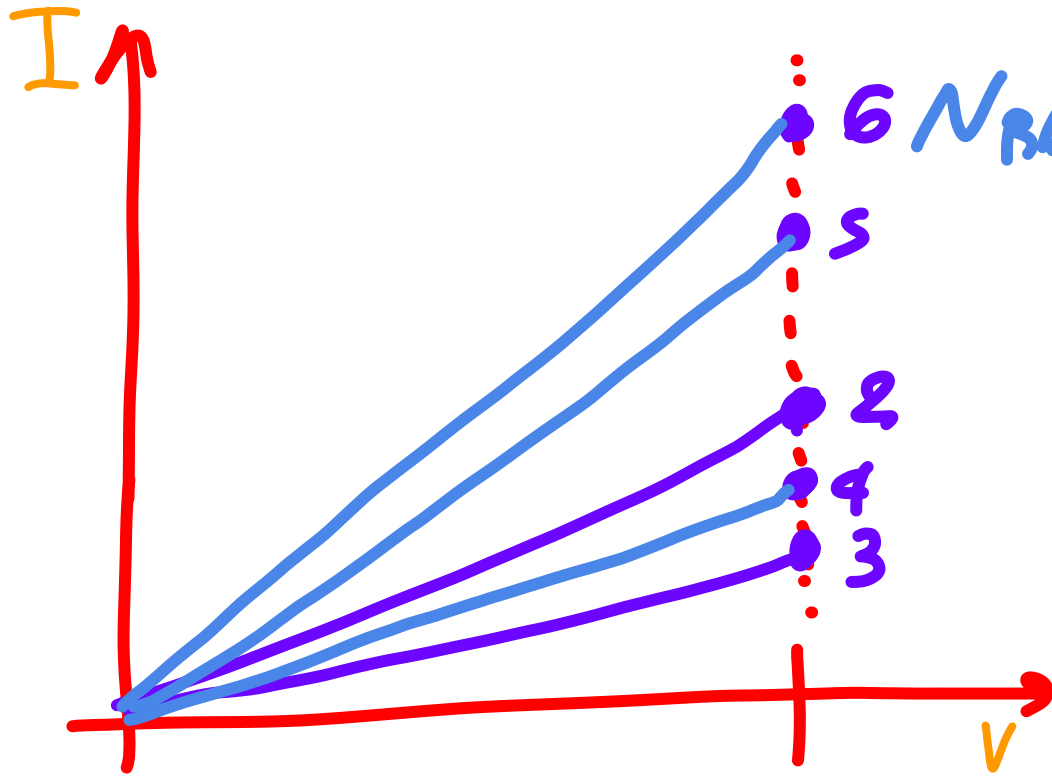
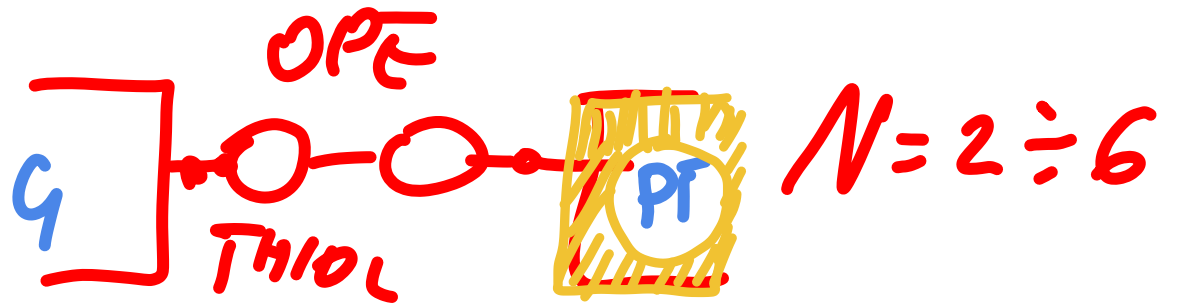
MORE DISTANT ELECTRODES \rightarrow WEAK OVERLAP BK
MOL. & ELECTRODES \rightarrow γ SMALLER \rightarrow NARROWER
PEAKS $I \downarrow$



→ MIX of 3 CONTRIB

→ Length \leftrightarrow I_{DS} \leftrightarrow NANO GAP WIDTH

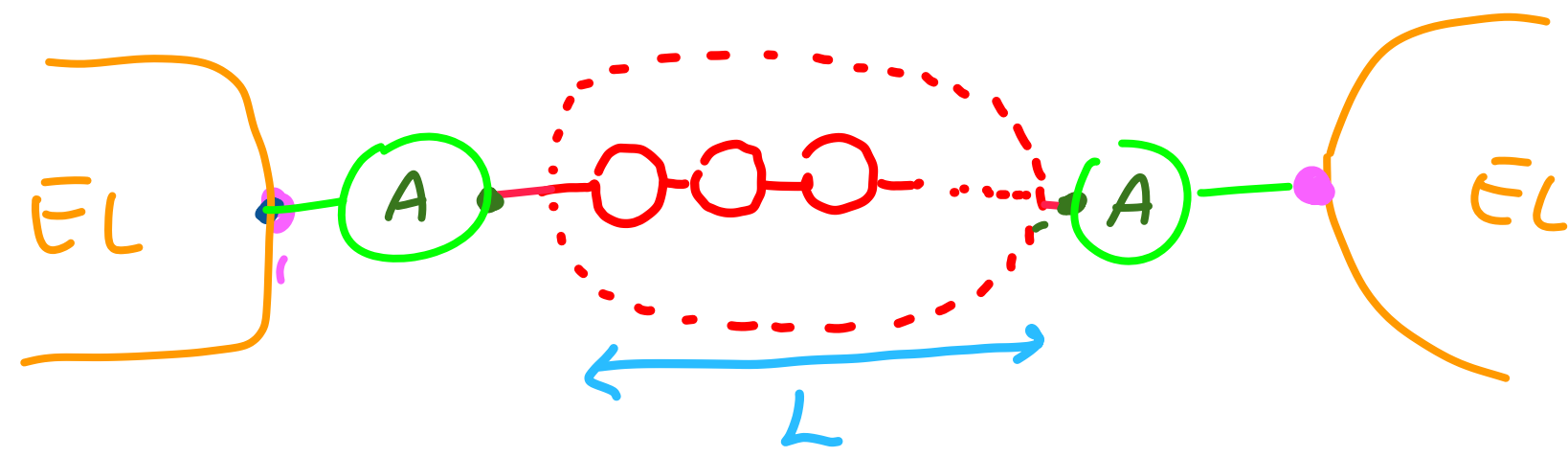
ex OPE



IN THIS CASE THE COMBINATION OF THE THREE CONTRIBUTIONS IS DIFFERENT DEPENDING ON THE N. OF RINGS

R MOLECULE LENGTH IMPACT ON CONDUCTION

FCAP



- 1) REDUCED HLG
- 2) MORE PEAKS IN TS
- 3) REDUCED BROADENING

I_{DS} DEPENDS ON HOW 1,2,3 COMBINE

WHAT WE LEARN:

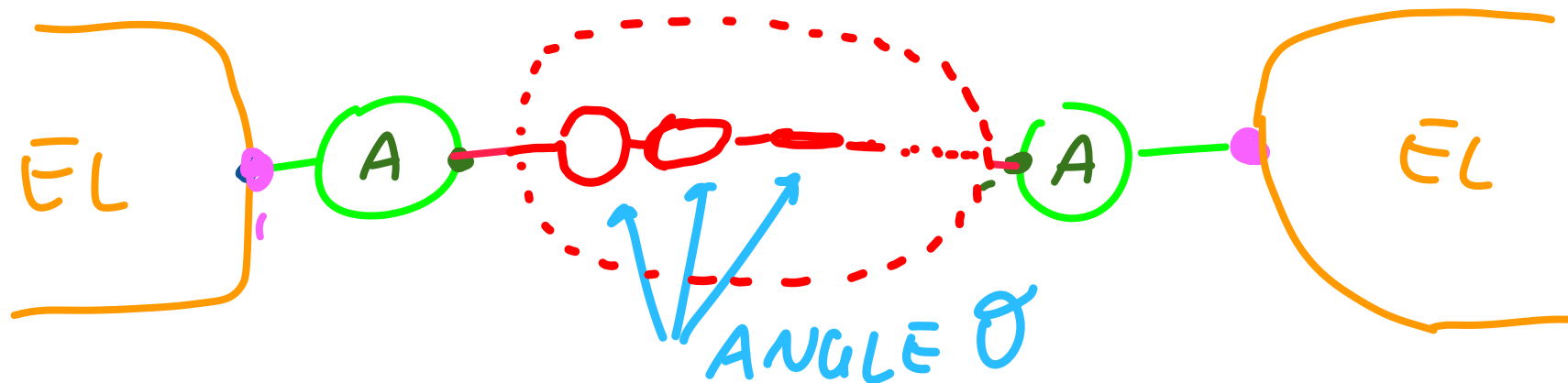
- ① IN CASE OF A TECH WHERE THE NGAP WIDTH IS FIXED THE LENGTH OF THE MOL. MUST BE CHOSEN ACCORDINGLY AND THE CONSEQUENCES IN TERMS OF CURRENT HAVE TO BE CONSIDERED → AN OPTIMAL MOL. SHOULD BE SELECTED

② IN CASE THE GAP WIDTH CAN
BE CONTROLLED THEN THE
RELATION WILL BE

→ DECIDE THE NO. &
NO. LENGTH

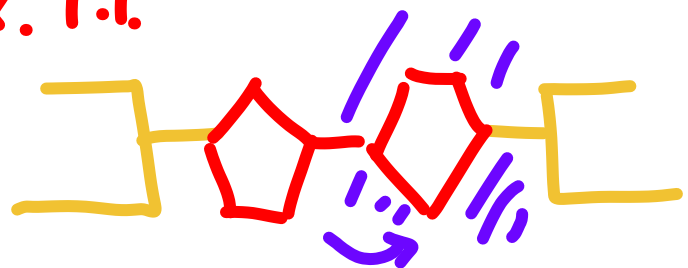
→ TREAT THE GAP AS A
CONSEQUENCE

EFFECT OF TORSION



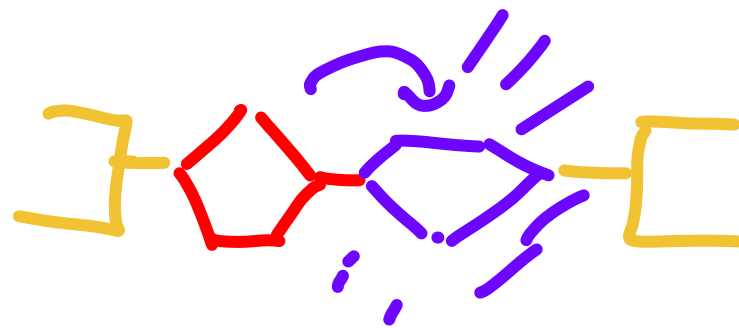
- DUE TO FREEDOM IN RINGS CONNECTION POINTS IN SOME MOLECULES
- INFLUENCED BY THE PROCESS OF ATTACHMENT AND BONDING TO ANCHORING AND GATES

ex. T.T.

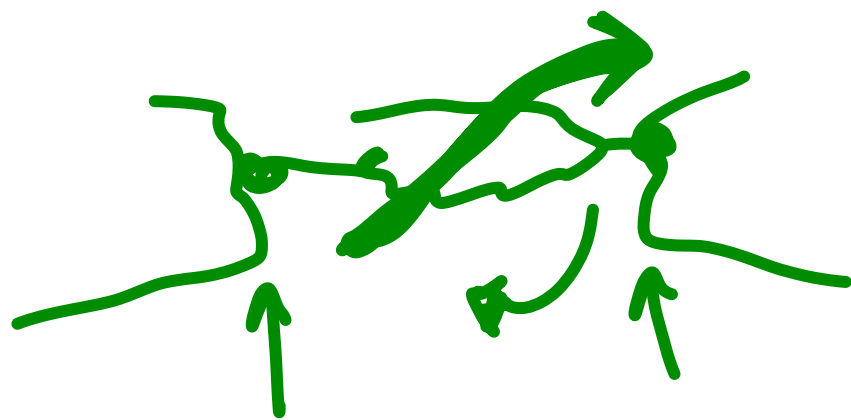


2 RINGS IN
SAME PLANE

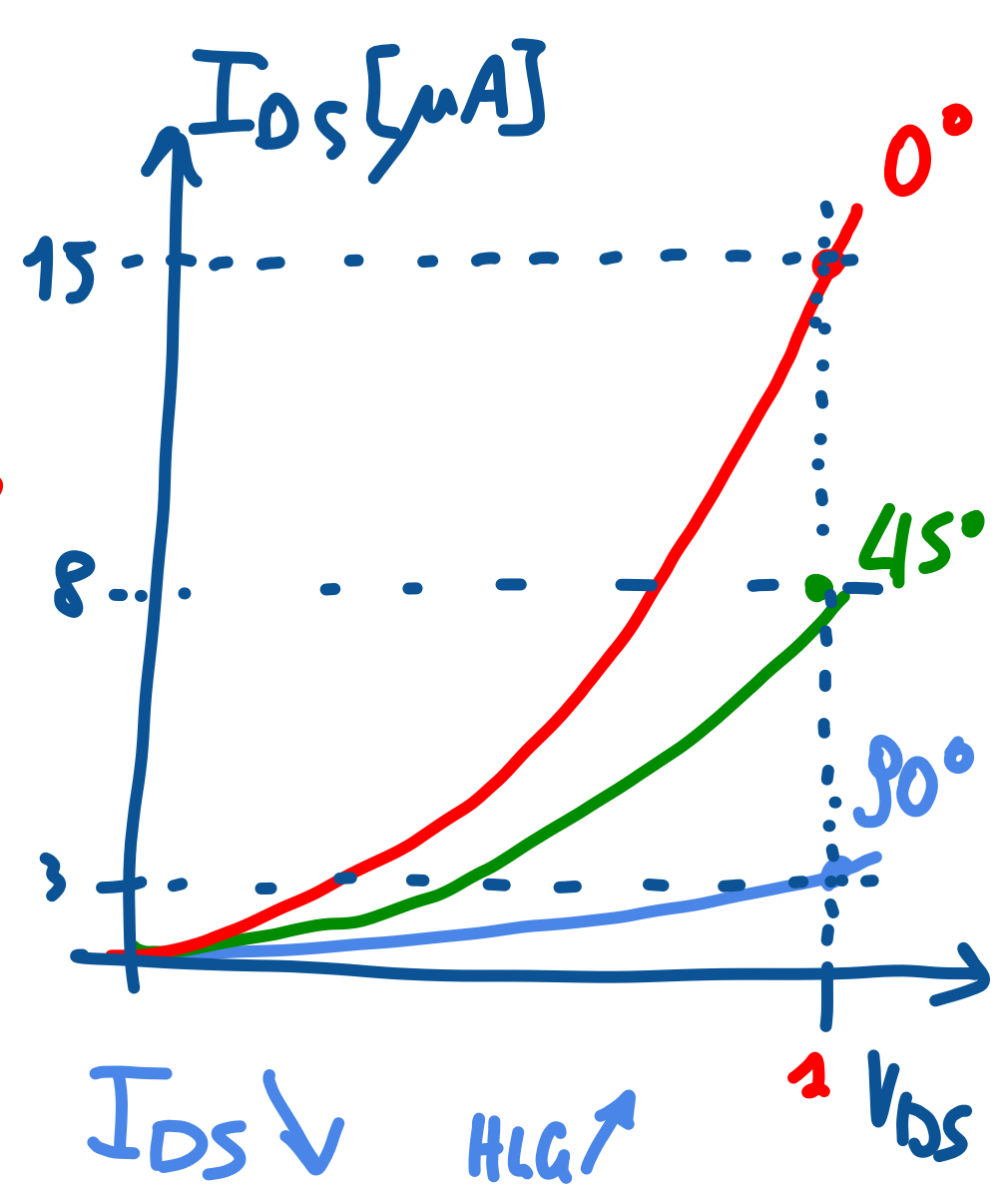
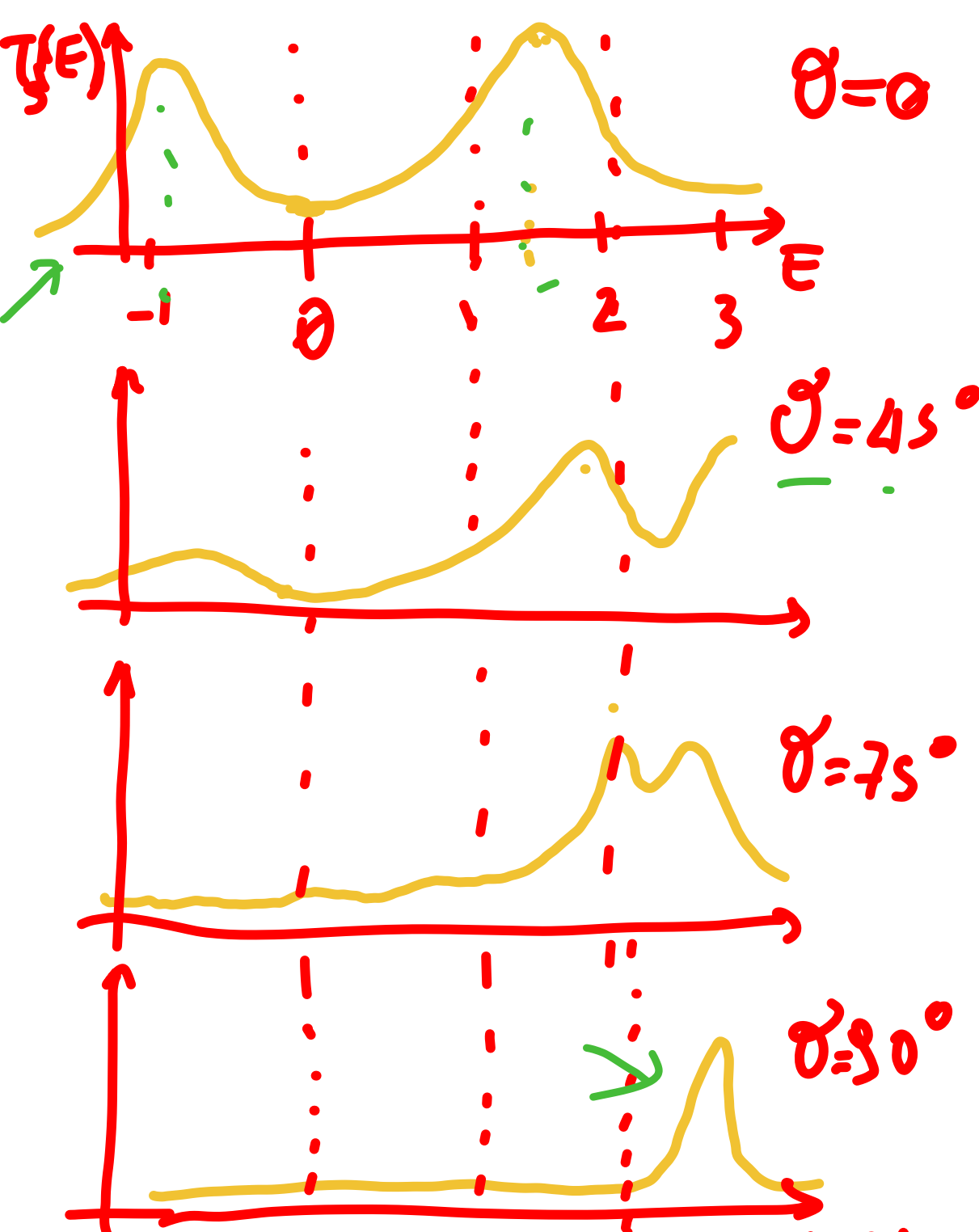
$$\theta = 0^\circ$$



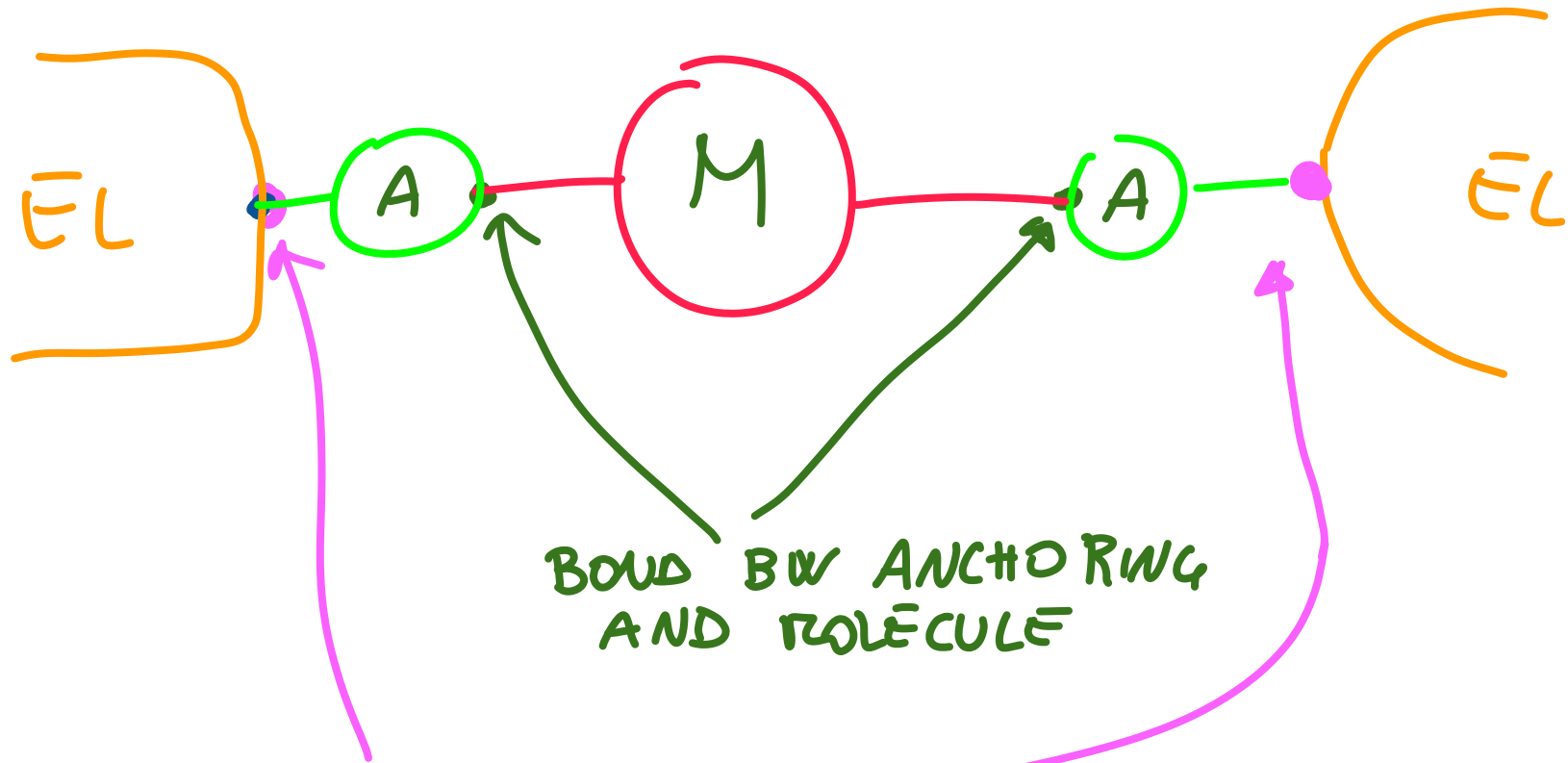
θ ROTATED
 $45^\circ, 75^\circ, 90^\circ$



TORSION MIGHT
HELP BONDS
CREATION



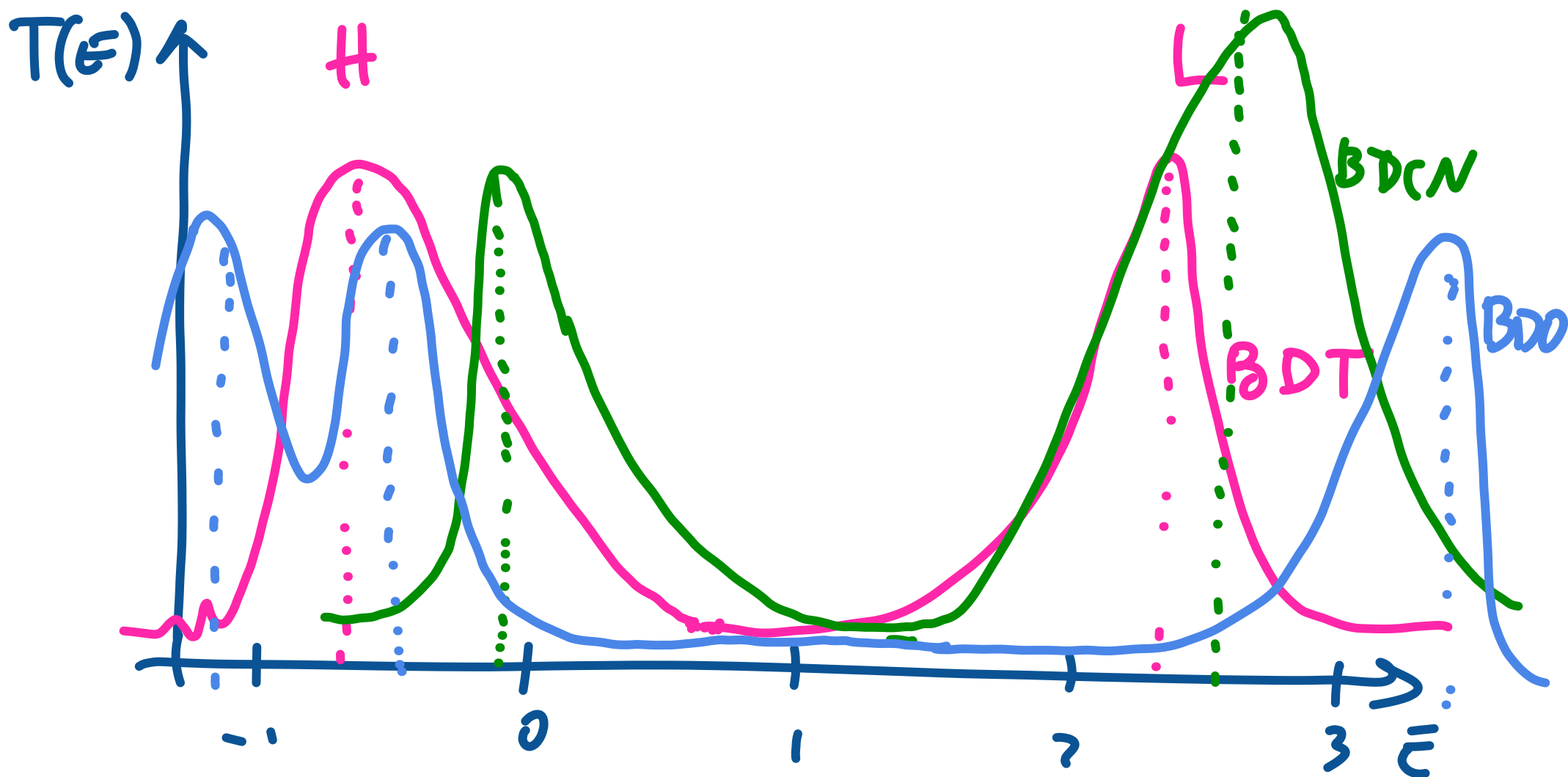
DEPENDENCE ON TYPE OF ANCHORING GROUP (LINKER)



BOND BW ANCHORING AND GOLD ELECTRODES

3 CASES: THIOL (-SH), CYANIDE (-CN), OXIGEN (-O)

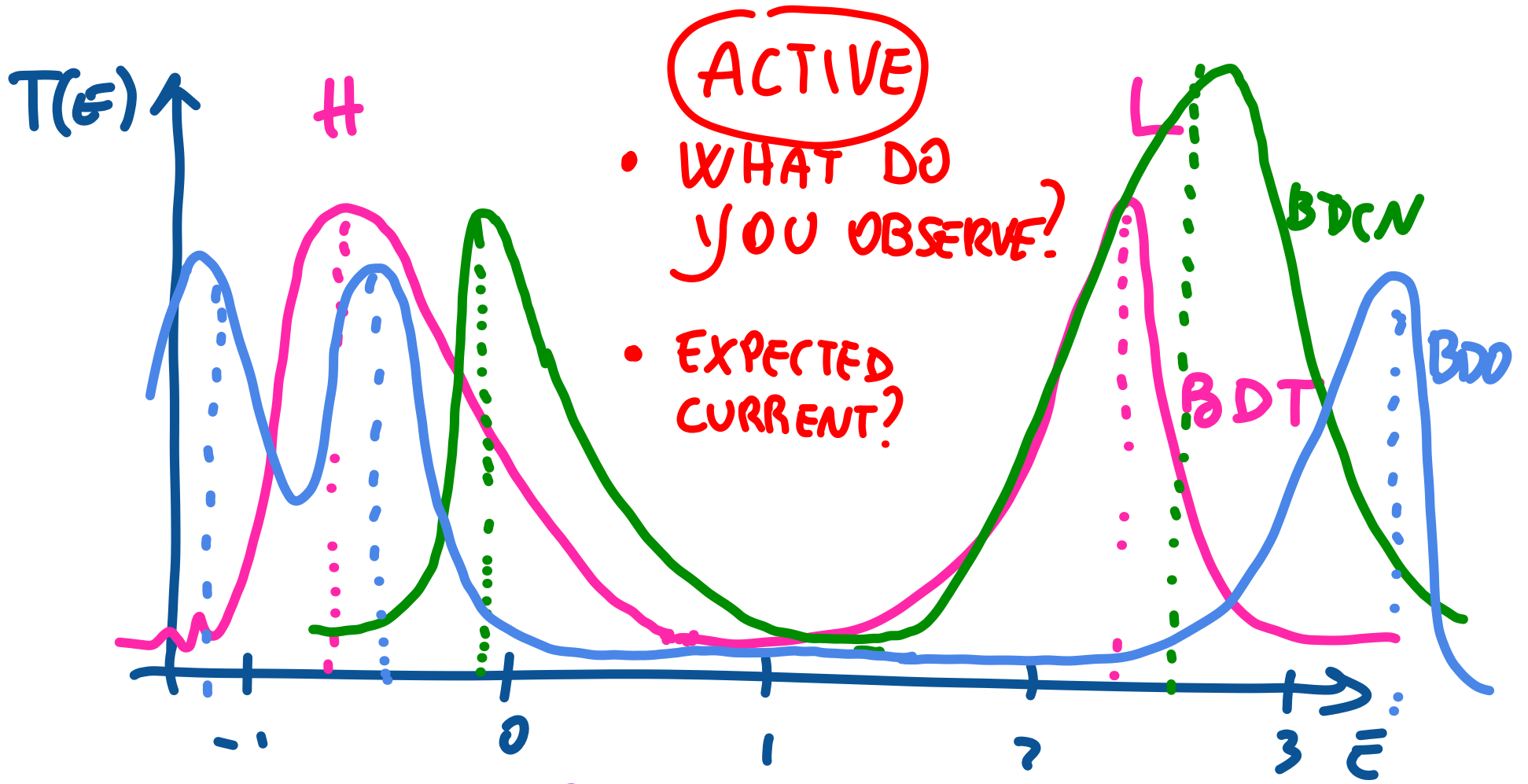
DEPENDENCY ON ANCHORING GROUPS



BDT - BENZENE DI THIOL

BDCN - BENZENE DI CYANIDE $C \equiv N$

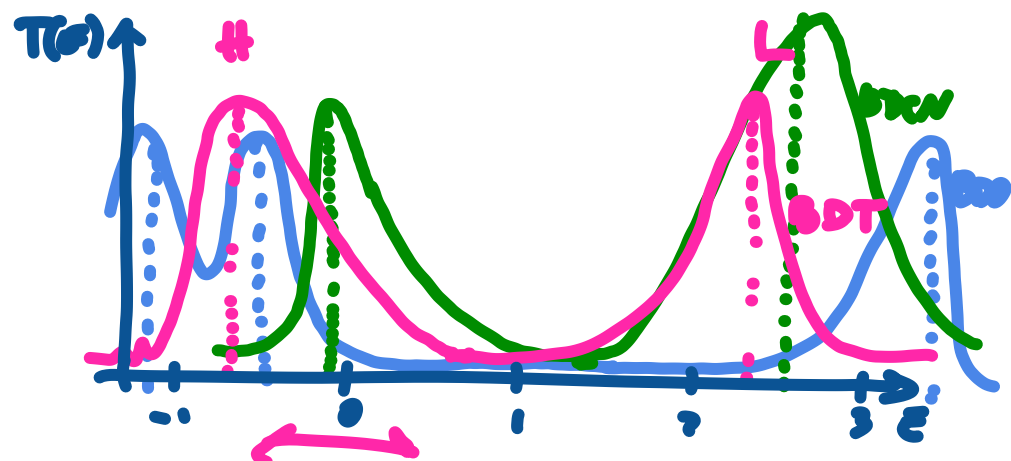
BDO - BENZENE DI OXYGEN



BDCN vs BDT ?

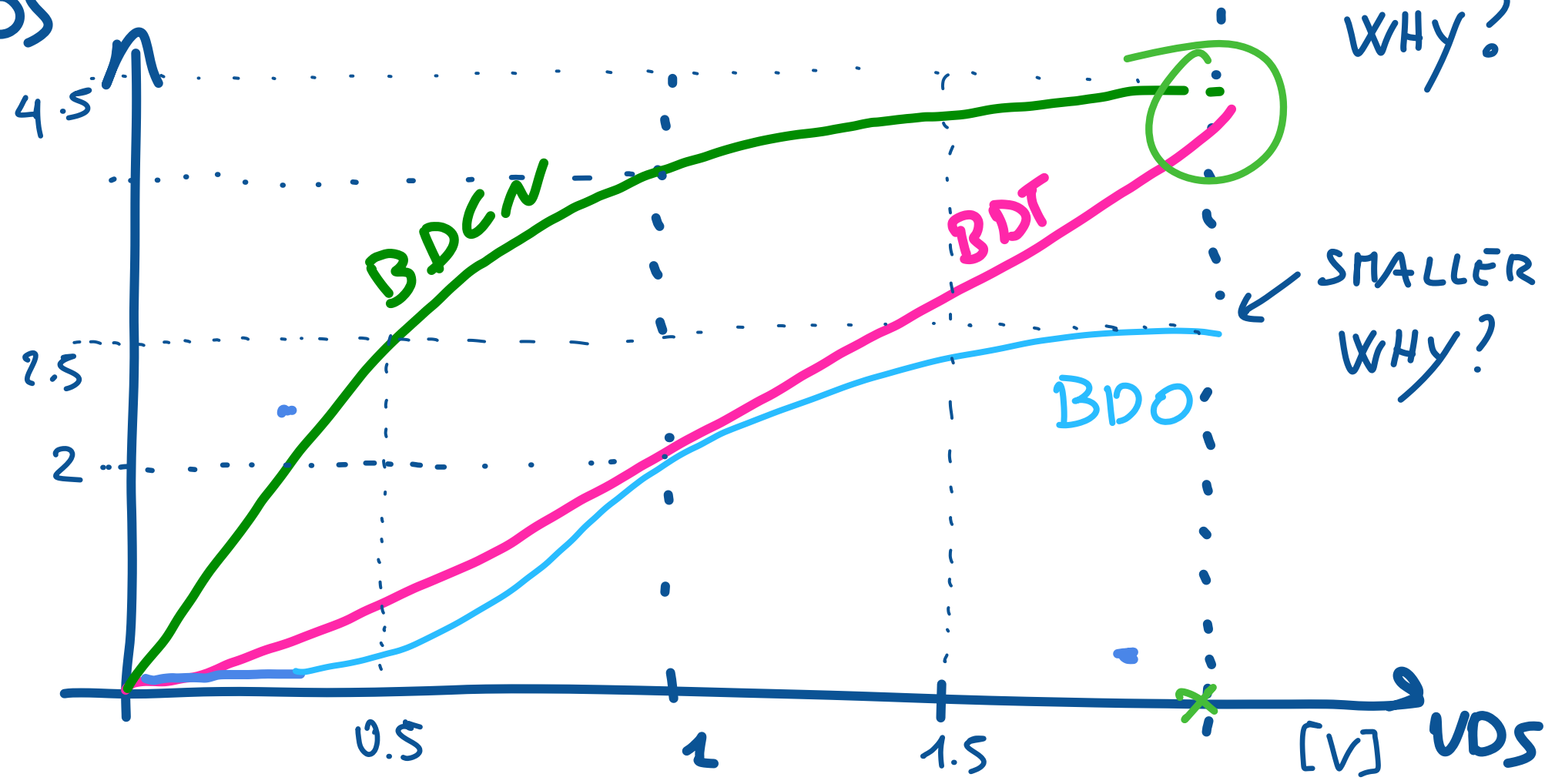
BDO vs BDT ?

BDO vs BDCN ?



VERY HIGH DIFFERENCE!

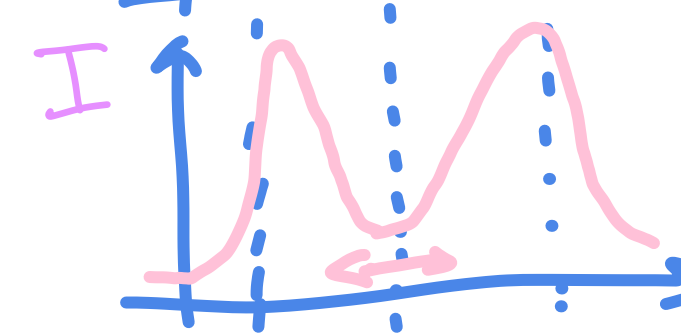
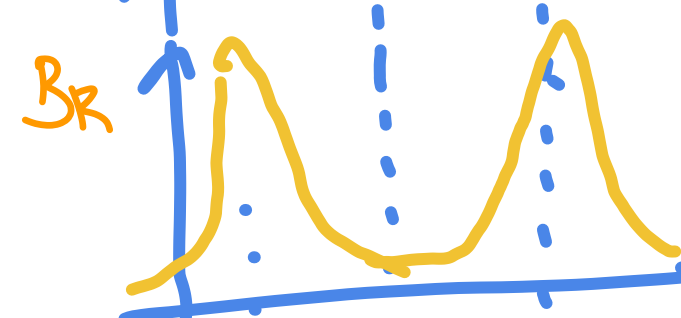
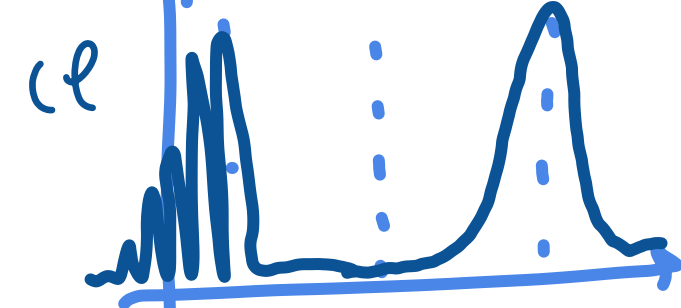
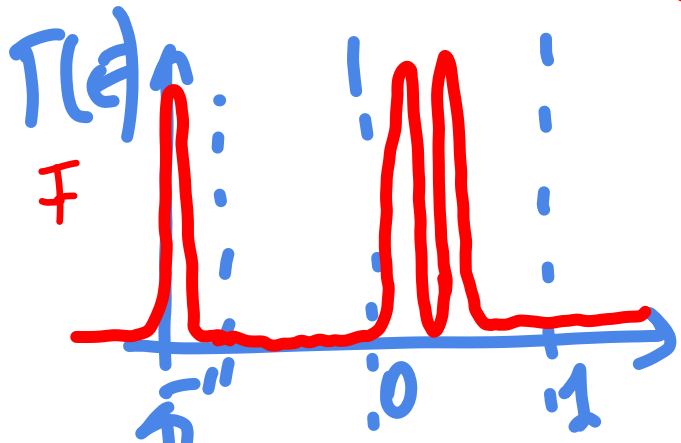
[mA]
 I_{DS}



WHY?

SMALLER WHY?

BENZENE + F, Cl, Br, I
 FLUORINE, CHLORINE, BROMINE, IODINE
 4, 3, 2.8, 2.5 \bar{E}_N



\bar{E}_N = ELECTRONEGATIVITY, i.e. HOW MUCH ELECTRONS ARE ATTRACTED

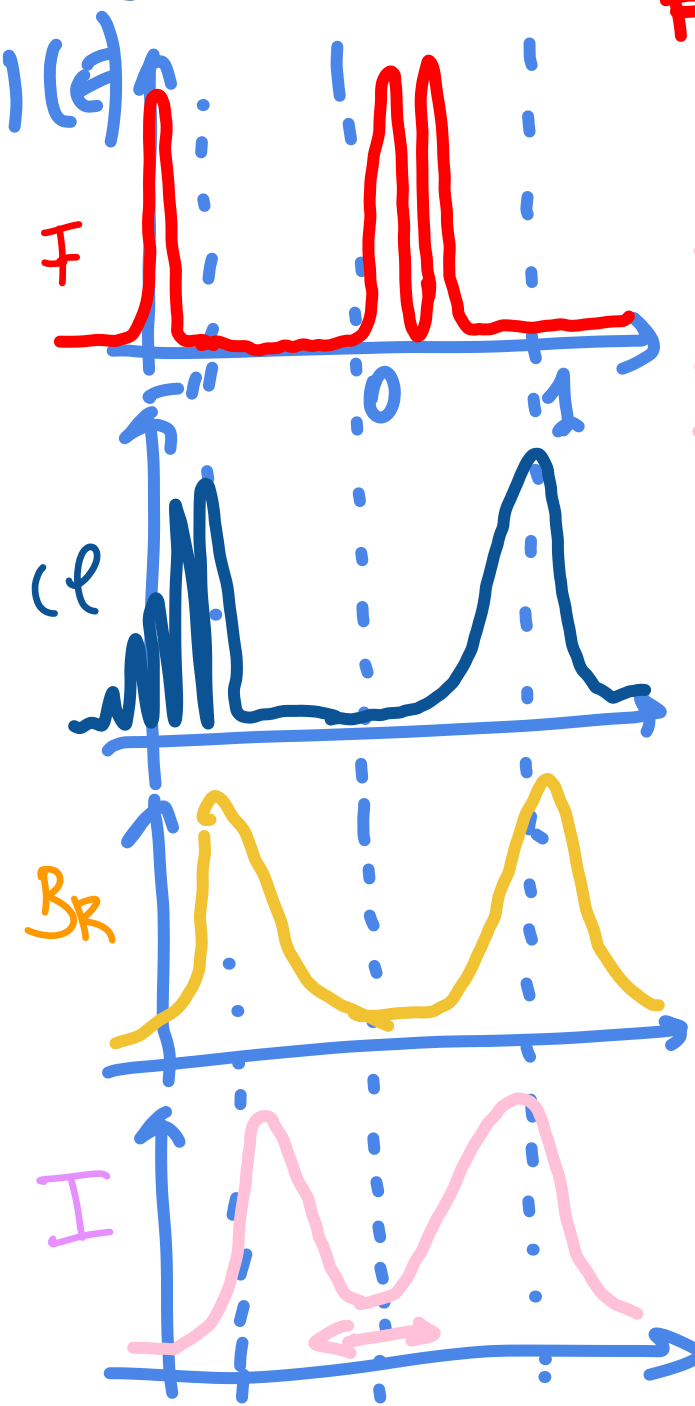
$\bar{E}_N \nearrow$ HIGH ATTRACTION

← if $\bar{E}_N \nearrow$

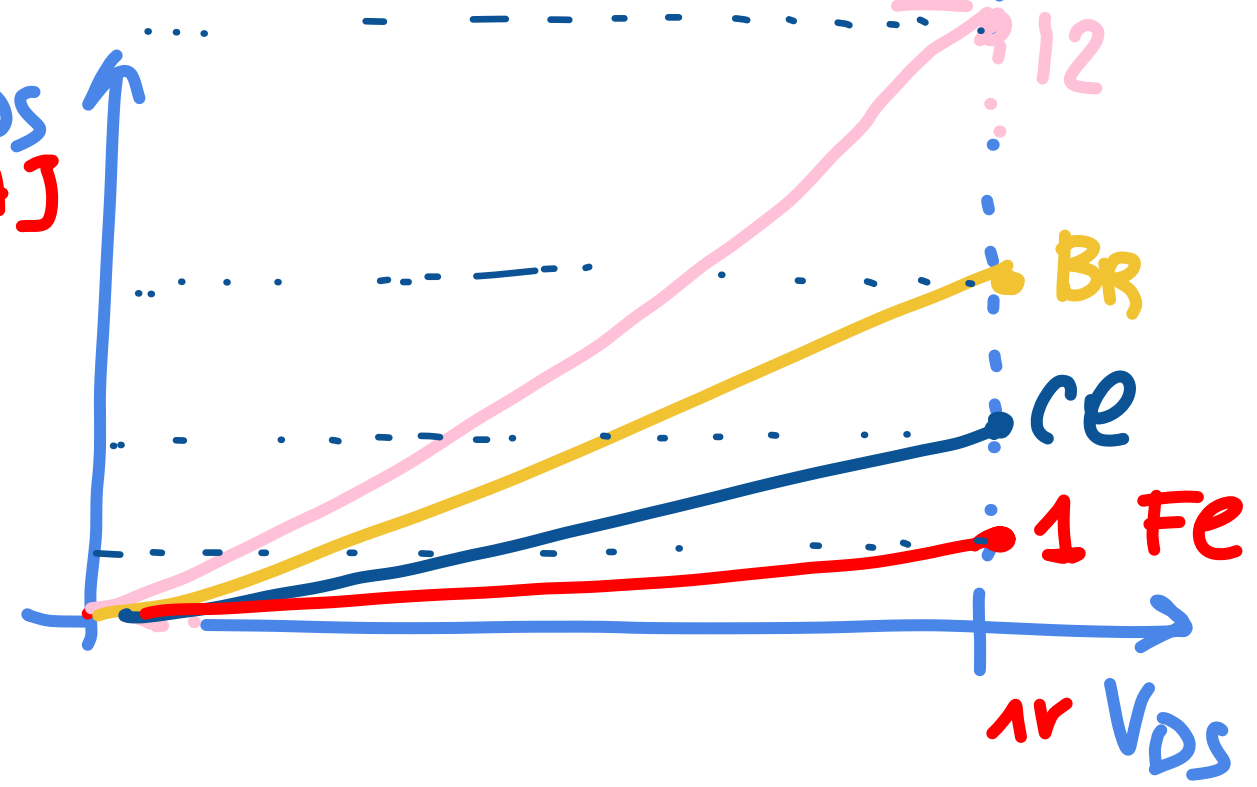
- HLG DECREASES
- BROADENING DECREASES
- N. OF PEAKS INCREASES

BENZENE + F FLUORINE, Cl CHLORINE, Br, I

9 3 2.8 2.5 \bar{E}_M



I_{DS}
[nA]

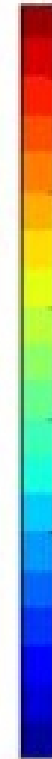
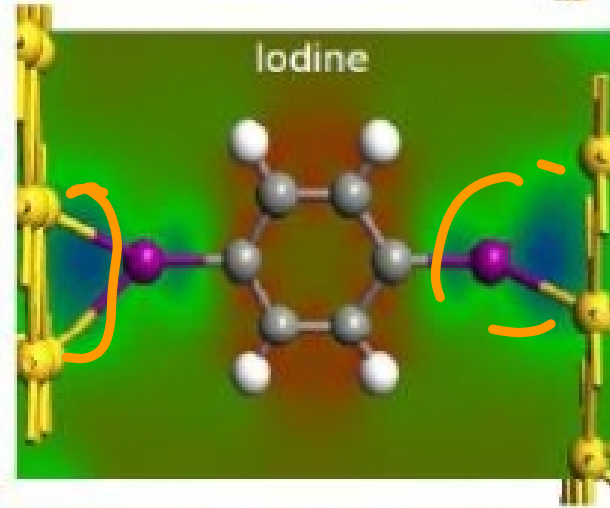
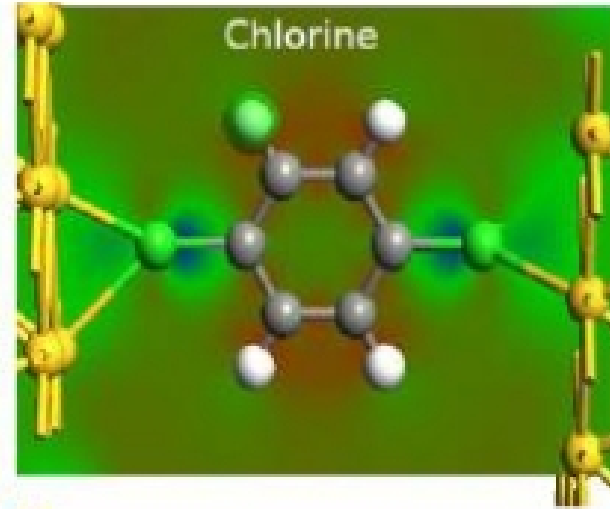
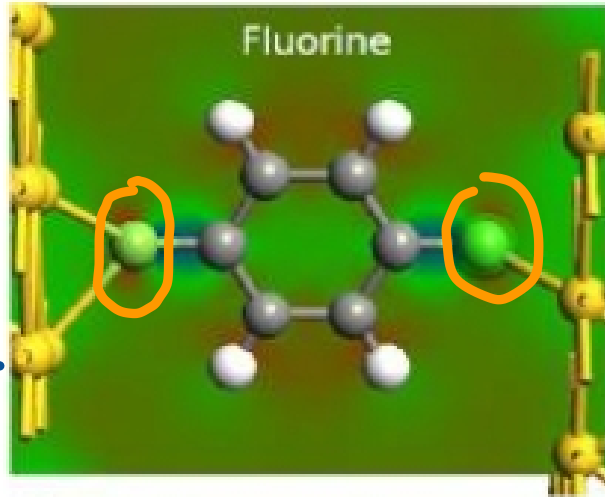


\bar{E}_N = ELECTRONEGATIVITY, i.e. HOW MUCH ELECTRONS ARE ATTRACTED

$\bar{E}_N \nearrow$ HIGH ATTRACTION

POTENTIAL ENERGY DISTRIBUTION IN SPACE 3D

HIGH ϵ_N
 MORE
 NEGATIVE
 CHARGE
 NEAR ELECT.
 ↓



HIGH POT.
 ENERGY
 → RED

LOW POT.
 ENERGY
 → BLUE

← POTENTIAL
 LESS
 AROUND
 LINKERS

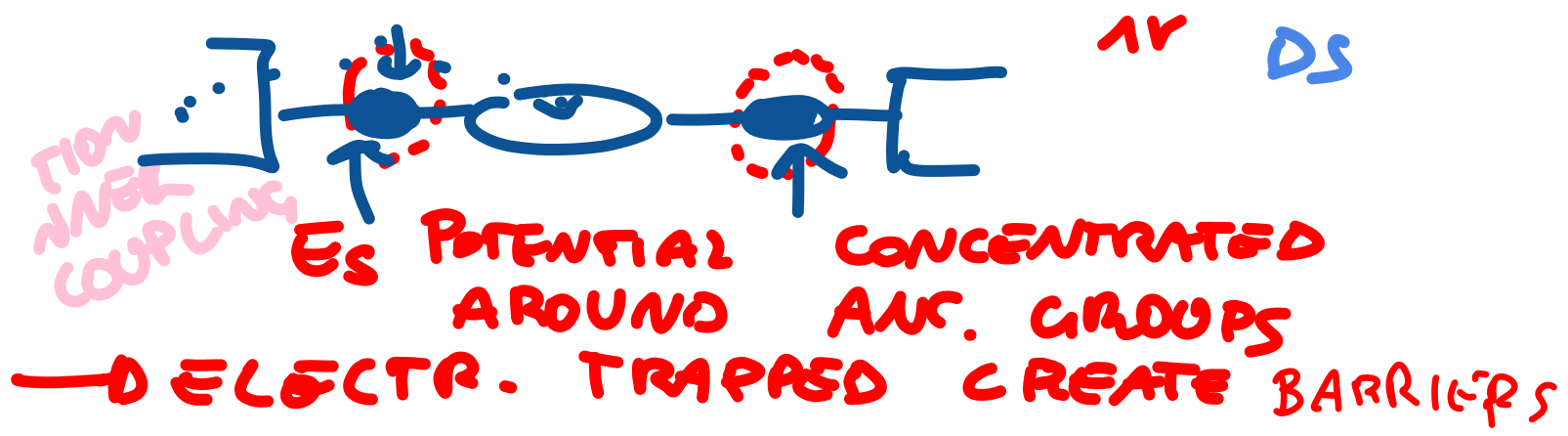
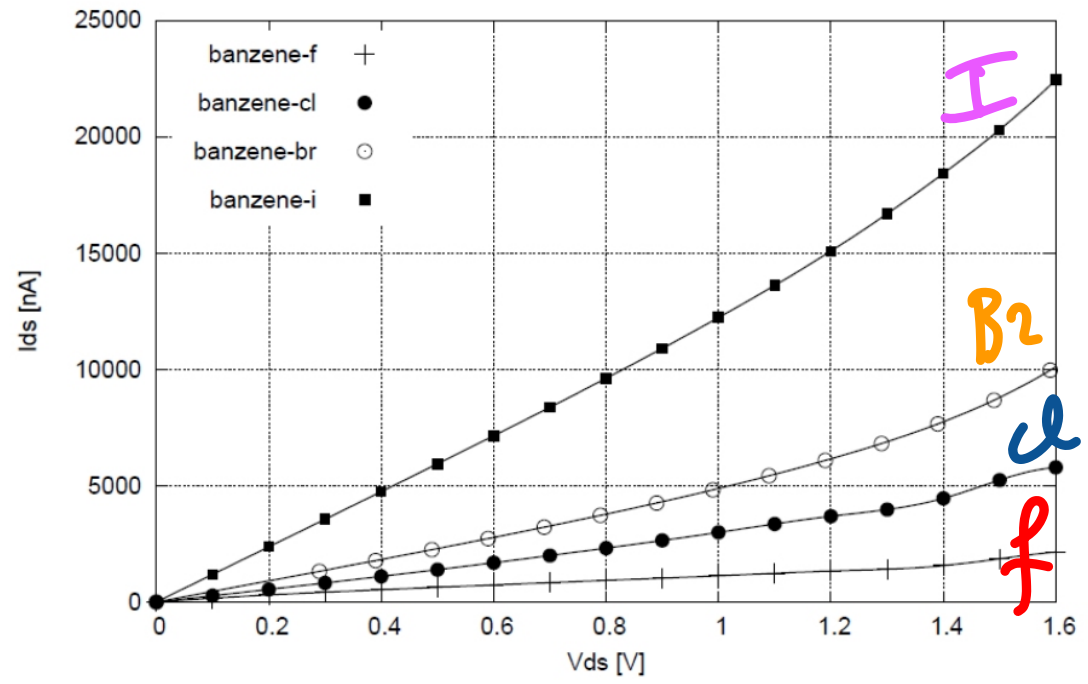
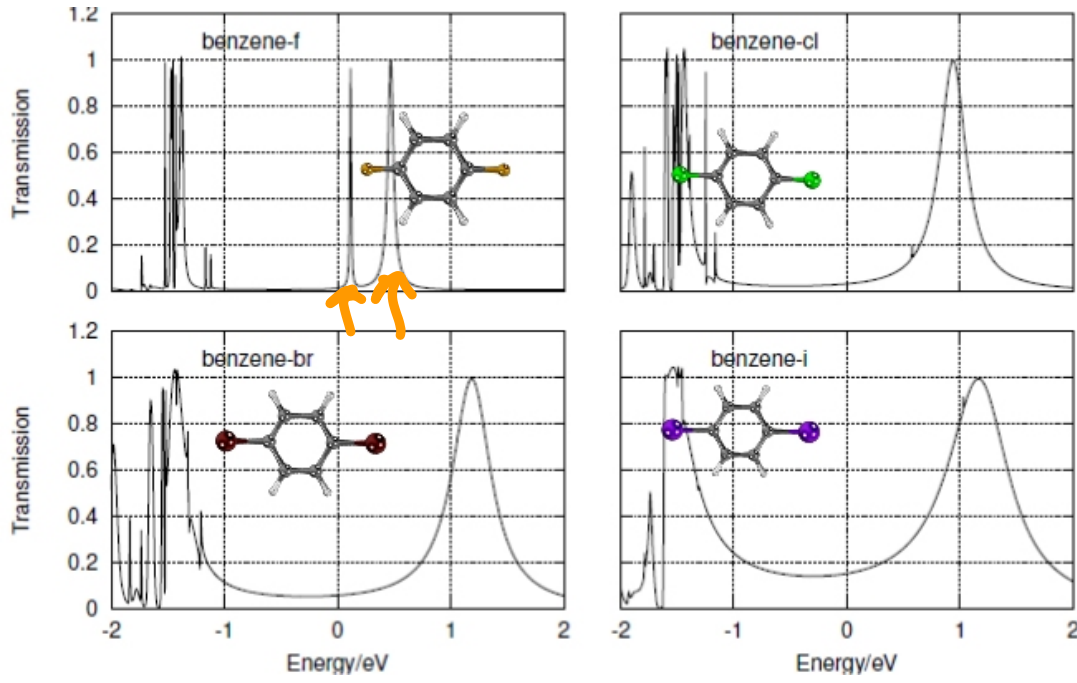
• BETTER
 COUPLING
 MORE BROADENING

HIGH
 BARRIER
 ↓
 LOW
 BROADENING

Zahir et al., "Molecular transistor circuits: From device model to circuit simulation," 2014 10.1109/NANOARCH.2014.6880492.

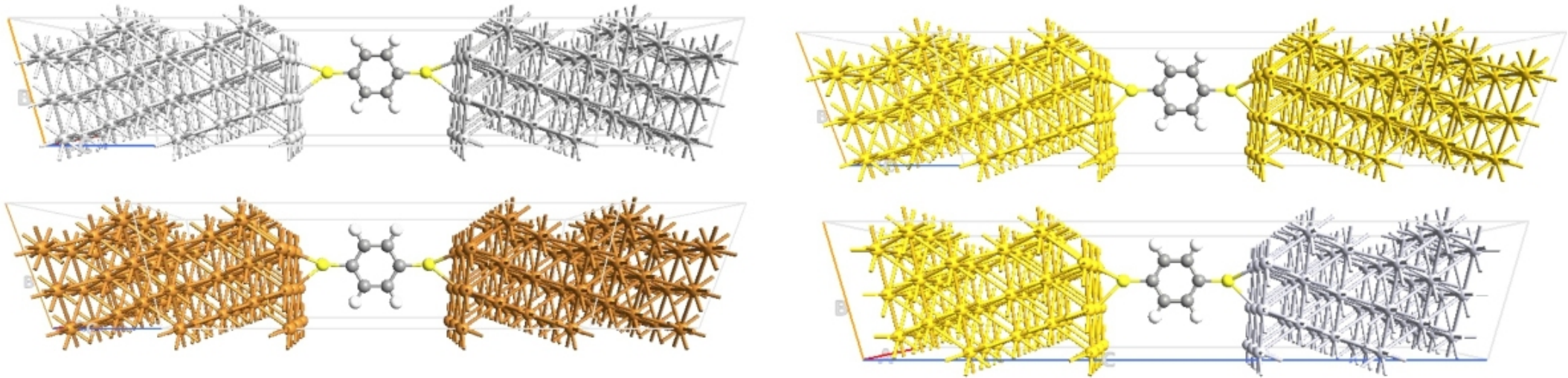
MORE ELECTRONEGATIVE LINKERS ATTRACT MORE THE ELECTRONS
 THAT "STAY" THERE → REPULSIVE FOR NEW EL.!

BENZENE + **F** FLUORINE 4, **Cl** CHLORINE 3, **Br** 2.8, **I** 2.5 E_M



IMPACT OF ELECTRODES

ACT AS CHARGE RESERVOIR



- NORMALLY NOBLE METALS ARE USED

- INFLUENCE THE ANCHORING

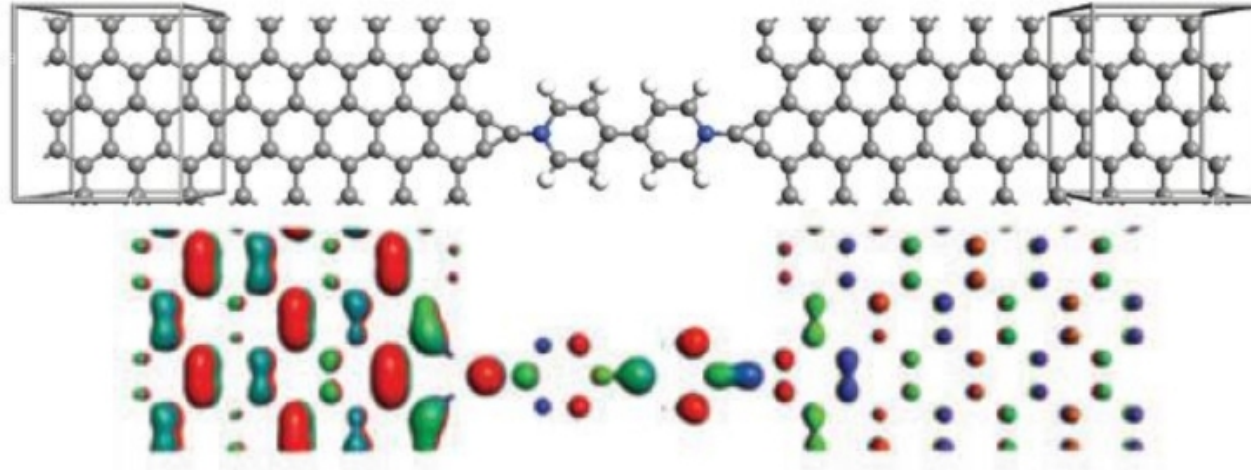
- IMPACT ON BROADENING

- DIFFERENT METALS FOR D & S →

FAVOUR
RECTIFICA-
TION
(DIODE)

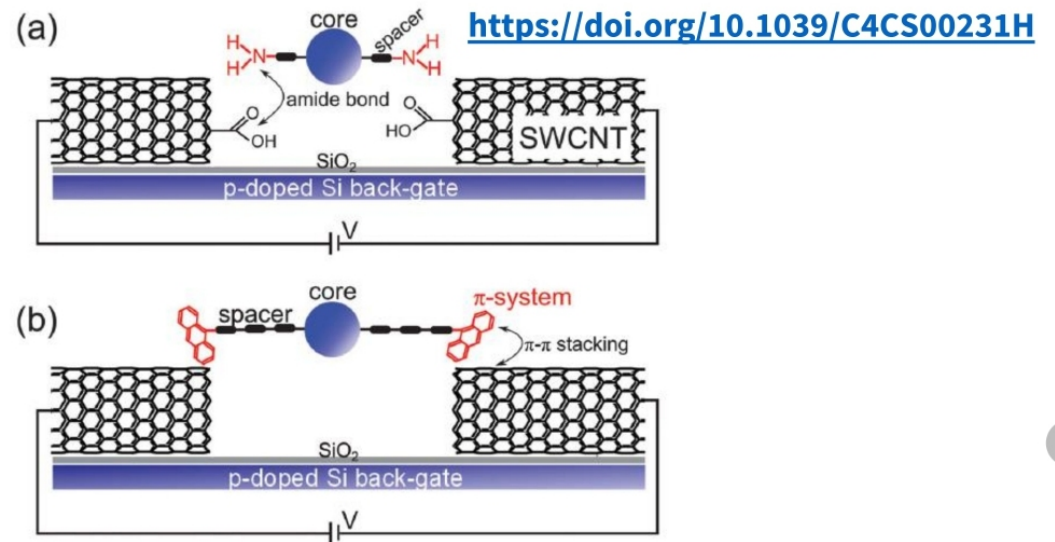
RECENTLY CARBON BASED ELECTRODES ARE INVESTIGATED

GRAPHENE



Li et al (2016). Distinctive Electron Transport on Pyridine-Linked Molecular Junction with Narrow Monolayer Graphene Nanoribbons 18. 10.1039/C6CP05007G.

CARBON NANOTUBES



CRISTALLIZATION

→ IDS FOR MOL. WIRE FROM TS TO IV

→ DEPENDENCY ON PARAMETERS

- LENGTH
- TORSION
- ANCHORING GROUP
- ELECTRODES